

30A 40V Cathode Common

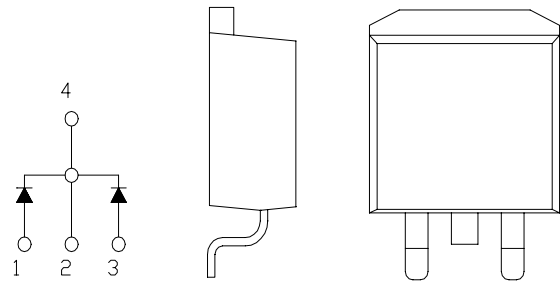
SBD Type : TCQ30B04

OUTLINE DRAWING

For High Frequency Rectification

FEATURES

- * High VRM SBD
- * Low Forward Voltage Drop and Low Noise
- * Fully Molded Isolation
- * Dual Diodes Cathode Common



Maximum Ratings

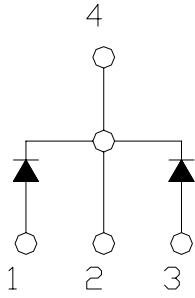
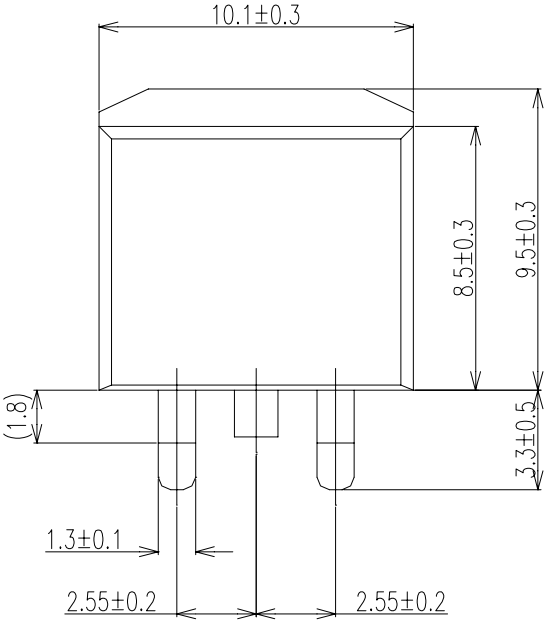
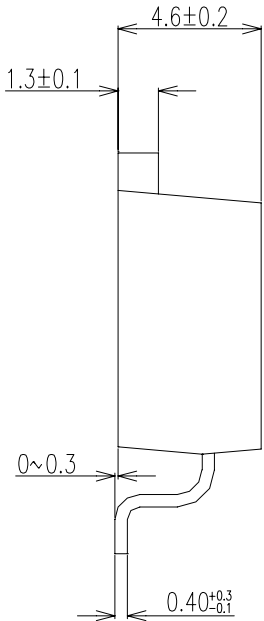
Approx Net Weight:1.4g

Rating	Symbol	TCQ30B04			Unit
Repetitive Peak Reverse Voltage	V _{RRM}	40			V
Average Rectified Output Current	I _O	30	Tc=100°C	50 Hz,Full Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	33.3			A
Surge Forward Current	I _{FSM}	150	50 Hz Full Sine Wave,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T _{jw}	- 40 to + 150			°C
Storage Temperature Range	T _{stg}	- 40 to + 150			°C

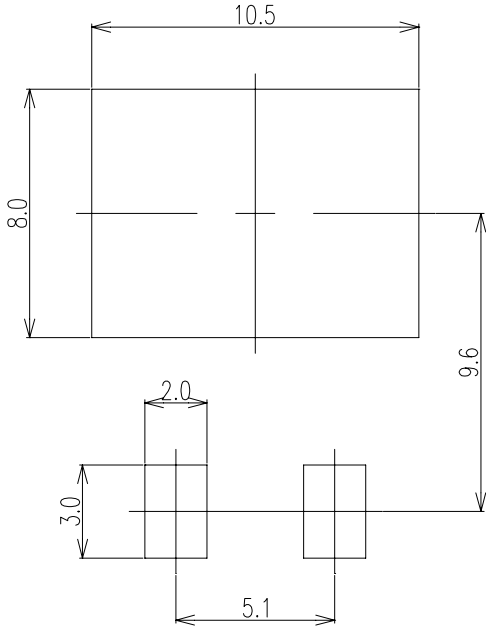
Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j=25^{\circ}C,V_{RM}=V_{RRM}$ per Diode	-	-	10	mA
Peak Forward Voltage	V_{FM}	$T_j=25^{\circ}C, I_{FM}=15A$ per Diode	-	-	0.61	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	1.5	$^{\circ}C/W$

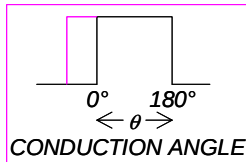
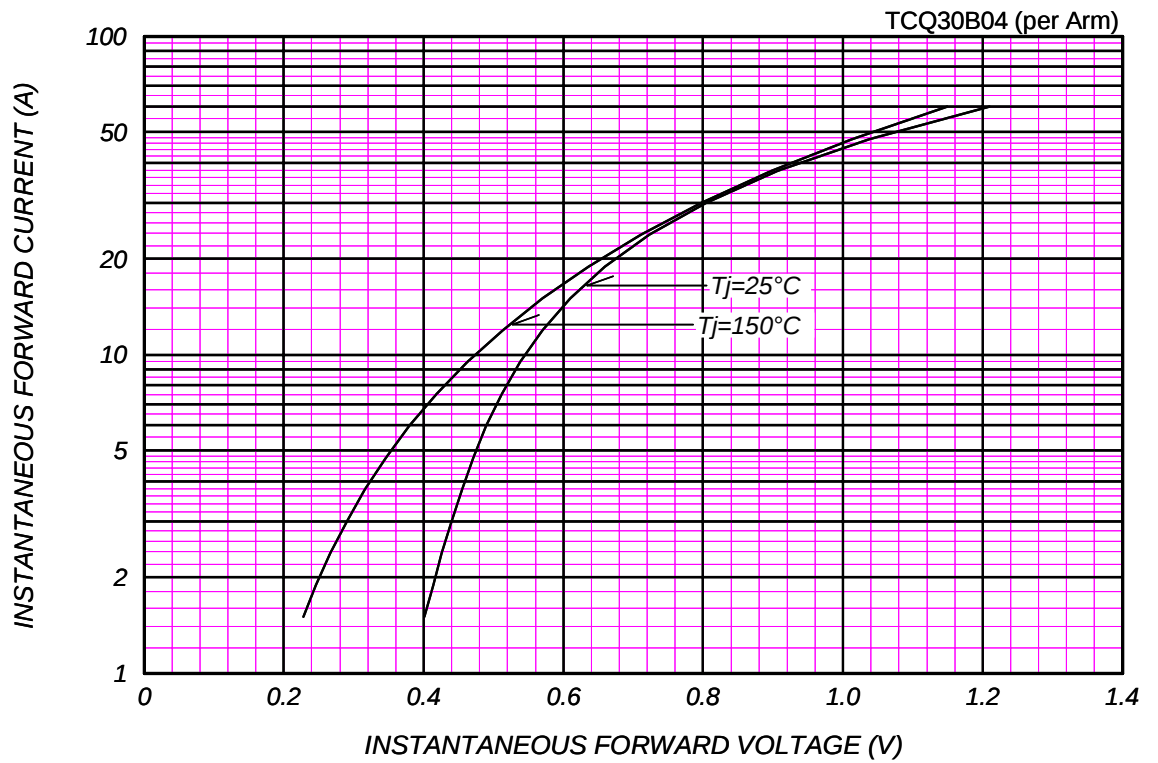
C_T_ OUTLINE DRAWING (Dimensions in mm)



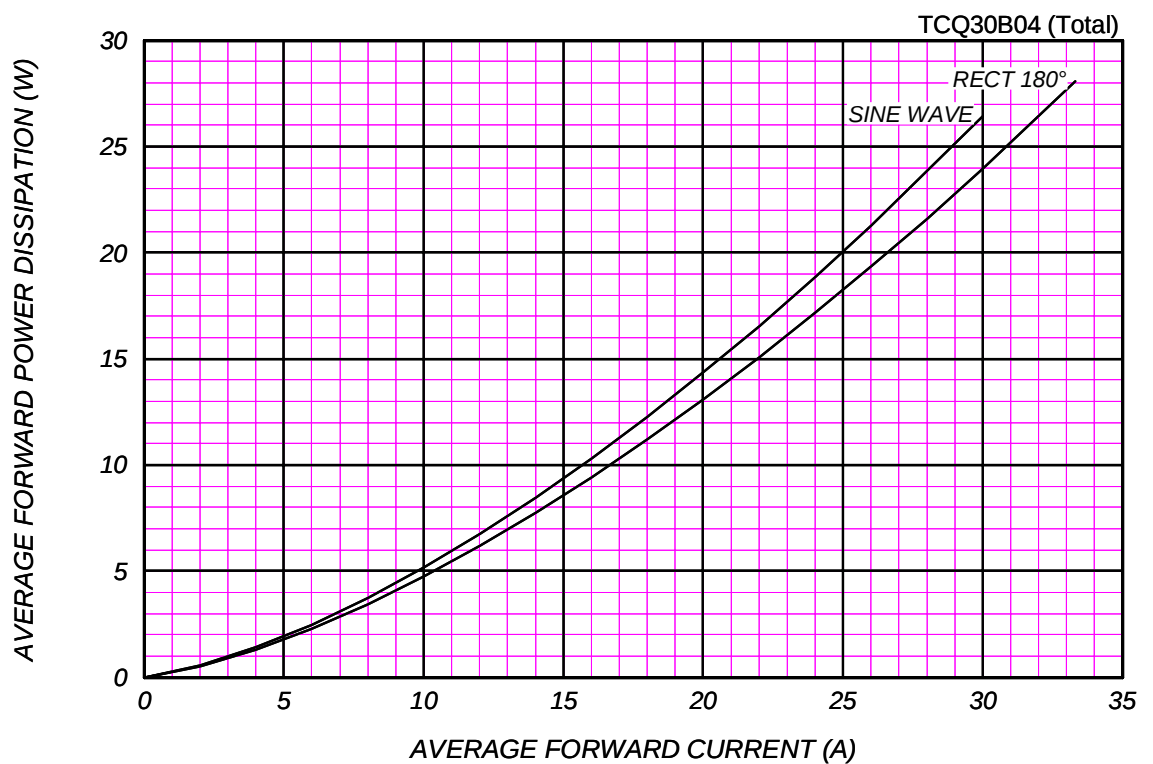
SOLDERING PAD



FORWARD CURRENT VS. VOLTAGE

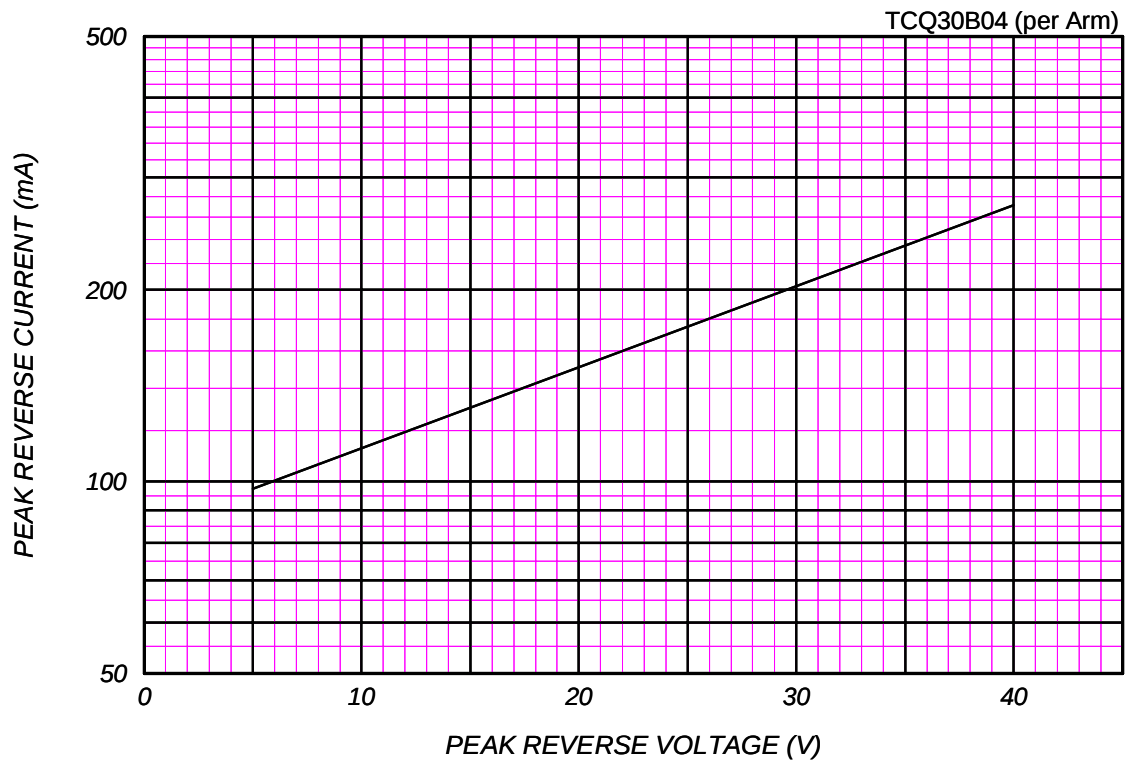


AVERAGE FORWARD POWER DISSIPATION

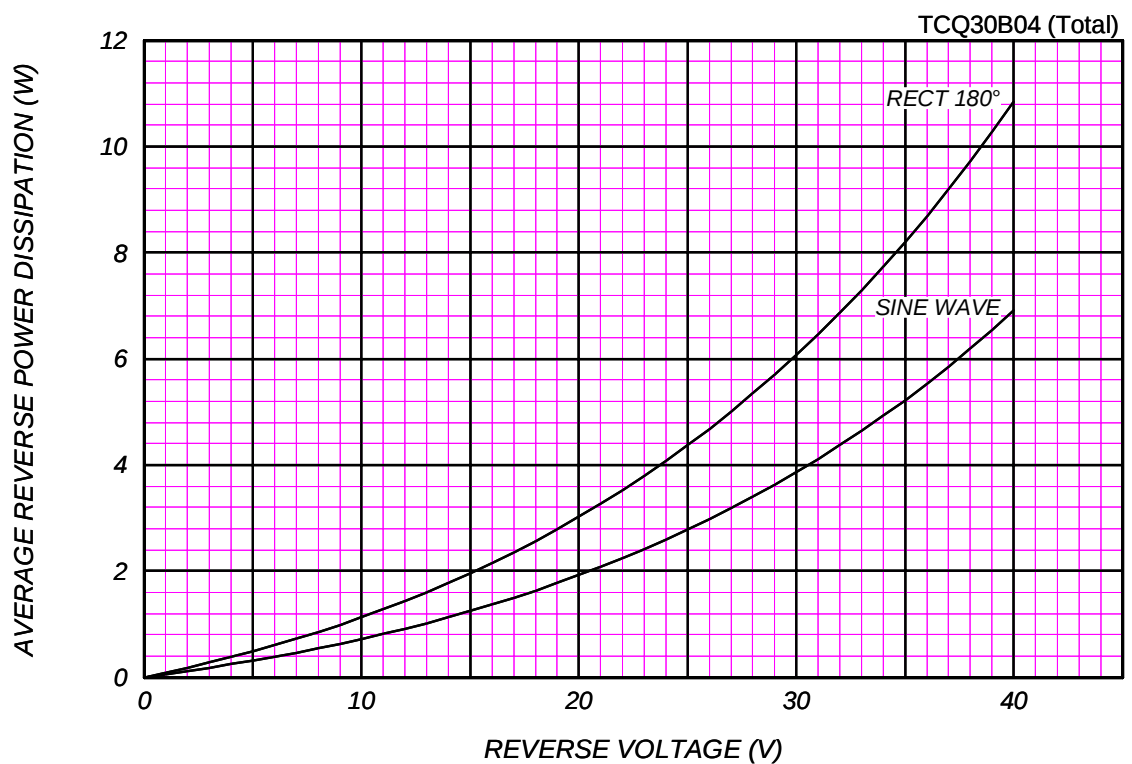


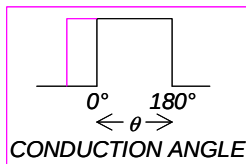
PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

$T_j = 150\text{ }^{\circ}\text{C}$



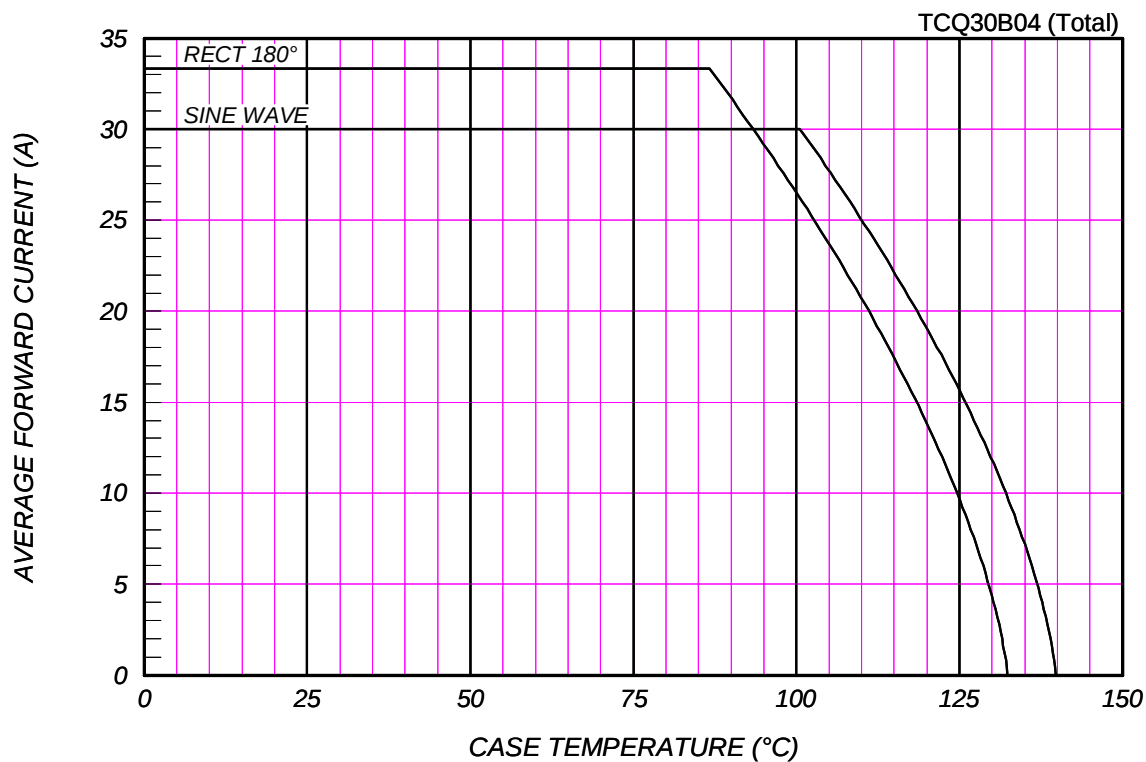
AVERAGE REVERSE POWER DISSIPATION





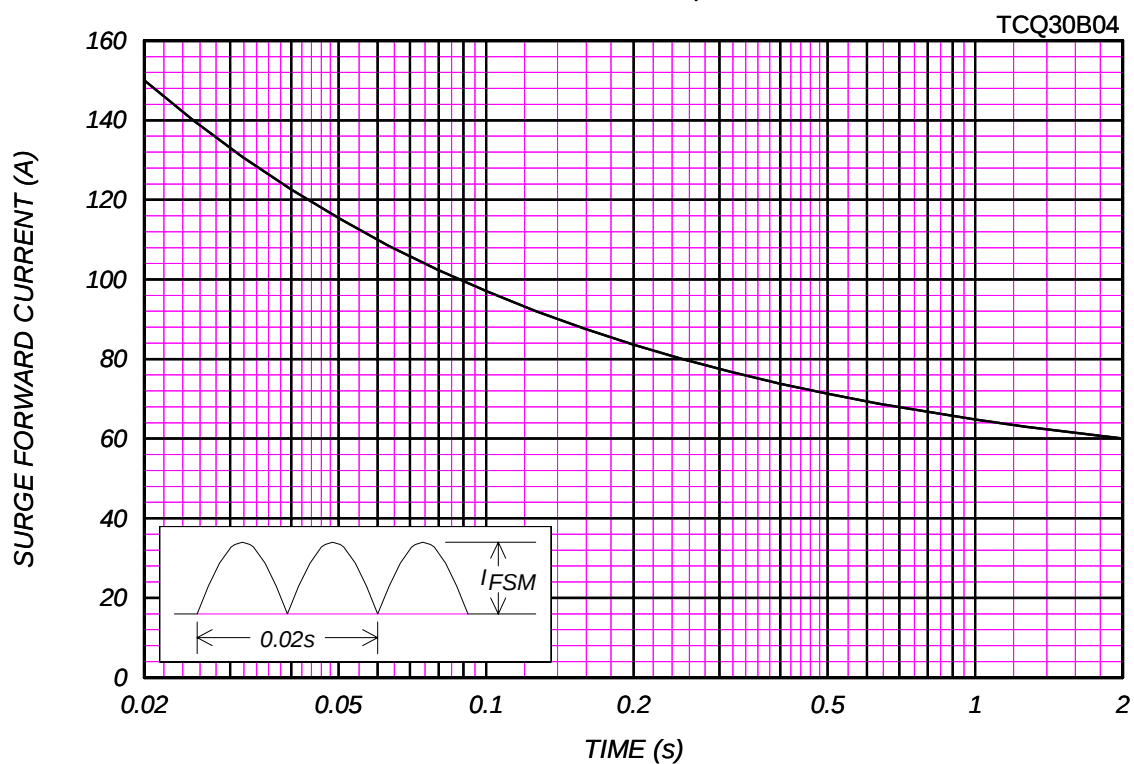
AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM}=40V$



SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load



JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

$T_j=25^{\circ}\text{C}$, $V_m=20\text{mV}_{\text{RMS}}$, $f=100\text{kHz}$, Typical Value

TCQ30B04 (per Arm)

